

Grain Size Effects on the Electromechanical Properties of donor-doped PZT-Ceramics



G. Picht^{1,2}, W. Rheinheimer², M. J. Hoffmann²

¹ Robert Bosch GmbH, Stuttgart, Germany, ² Ceramics in Mechanical Engineering, Institute of Applied Materials, Karlsruhe Institute of Technology, Karlsruhe, Germany

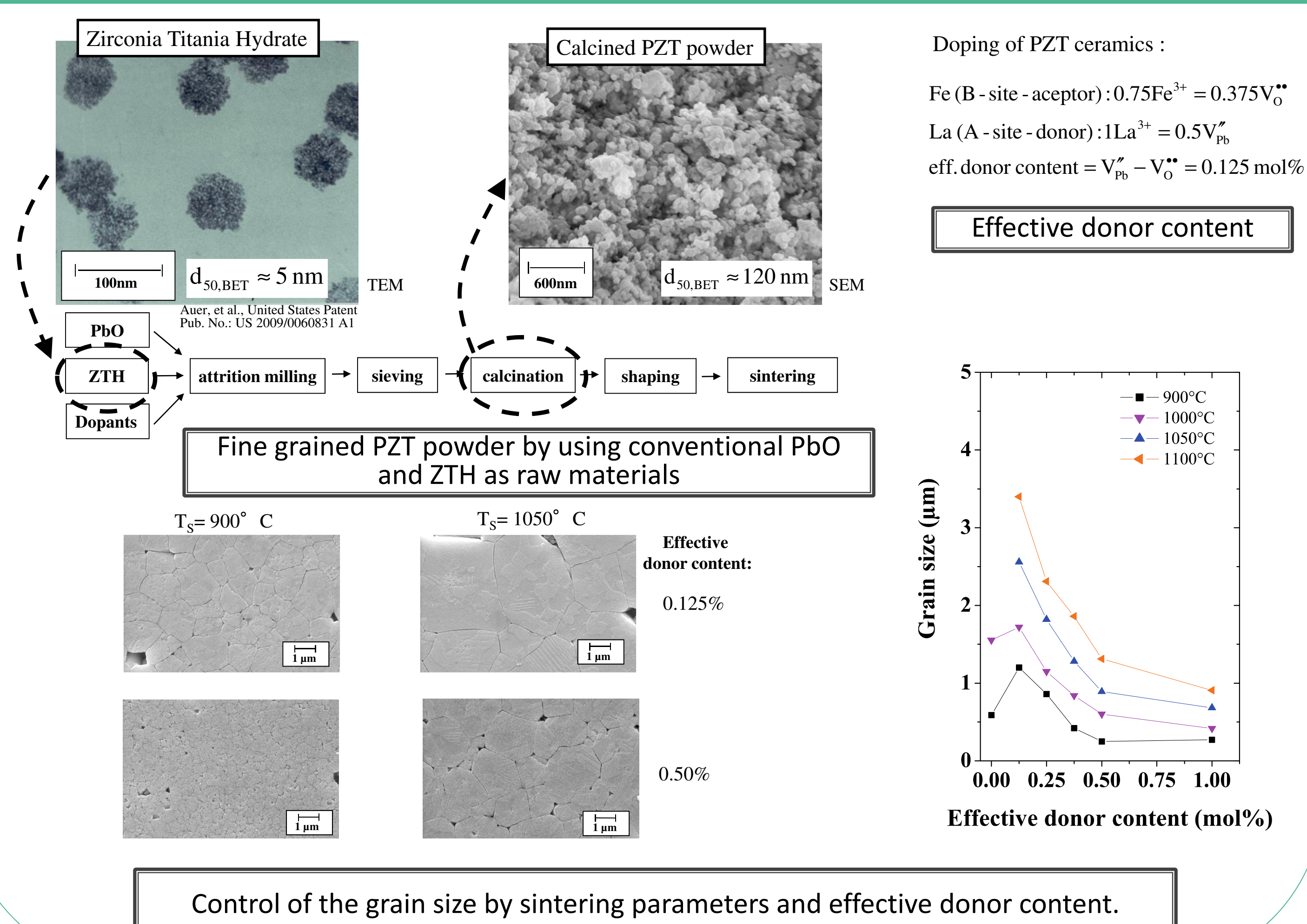
Motivation, Methods and Objectives

Piezoelectric ceramics of the solid solution $\text{PbZr}_{1-x}\text{Ti}_x\text{O}_3$ (PZT) are state of the art materials in sensor applications such as accelerometers and ultrasonic sensors. It is known from literature that their electromechanical properties are grain size dependent.

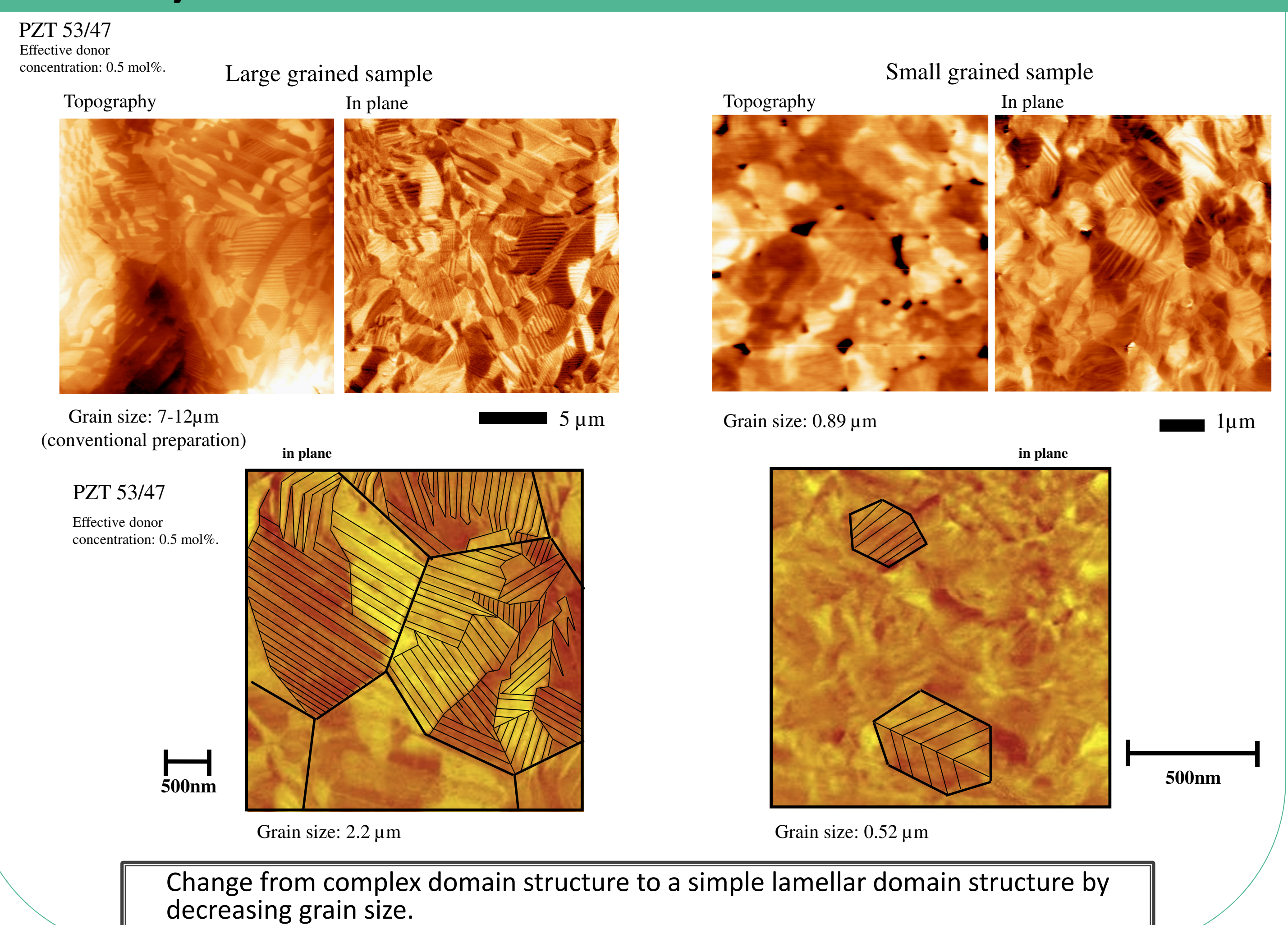
The current study analysed the grain size effect for different Zr/Ti-ratios and different donor concentrations. Dense ceramics with a grain size between 0.3 – 10.0 μm were obtained by varying the sintering temperature from 875°C to 1250°C. Hereby the Ti content was varied between 45 to 52 mol% with a fixed concentration of 1 mol% La as dopant. In a second step the Ti content was fixed at 47 mol% and the doping content was varied from 1 mol% La to co-doping with 1 mol% La and 0.75 mol% Fe.

While decreasing the grain size of the material a critical size was found, at which the domain structure changes significant from complex 3-D structures to simple lamellar patterns. This is in correlation with a suppression of the distortion of the perovskite lattice below the critical grain size as shown by XRD and Raman experiments. Small and large signal dielectric and piezoelectric properties show changes in non-180° domain switching as well as changes of the intrinsic piezoelectric properties by decreasing the grain size. It is demonstrated that the critical grain size is mostly related to the amount of donor dopant.

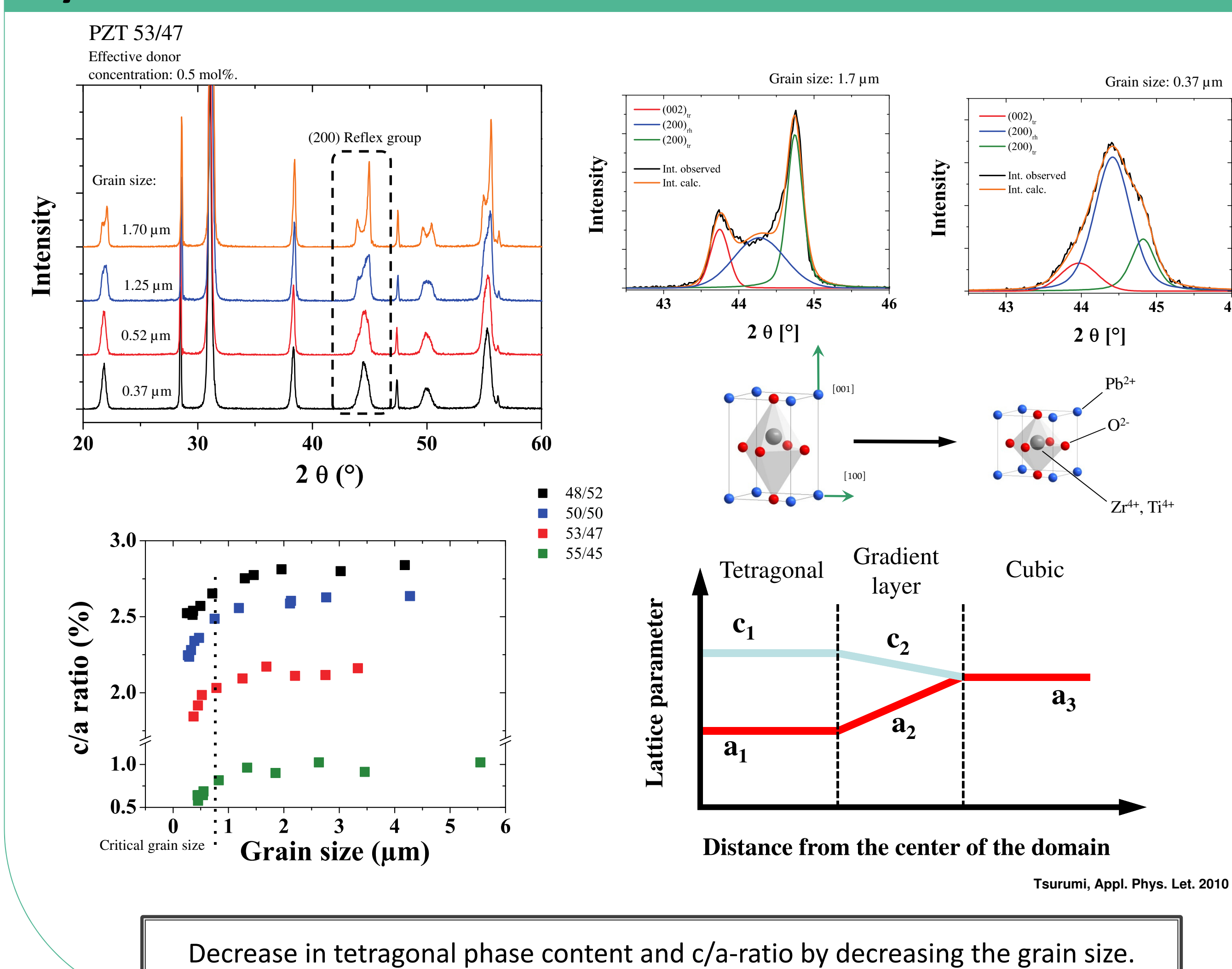
Synthesis and microstructure



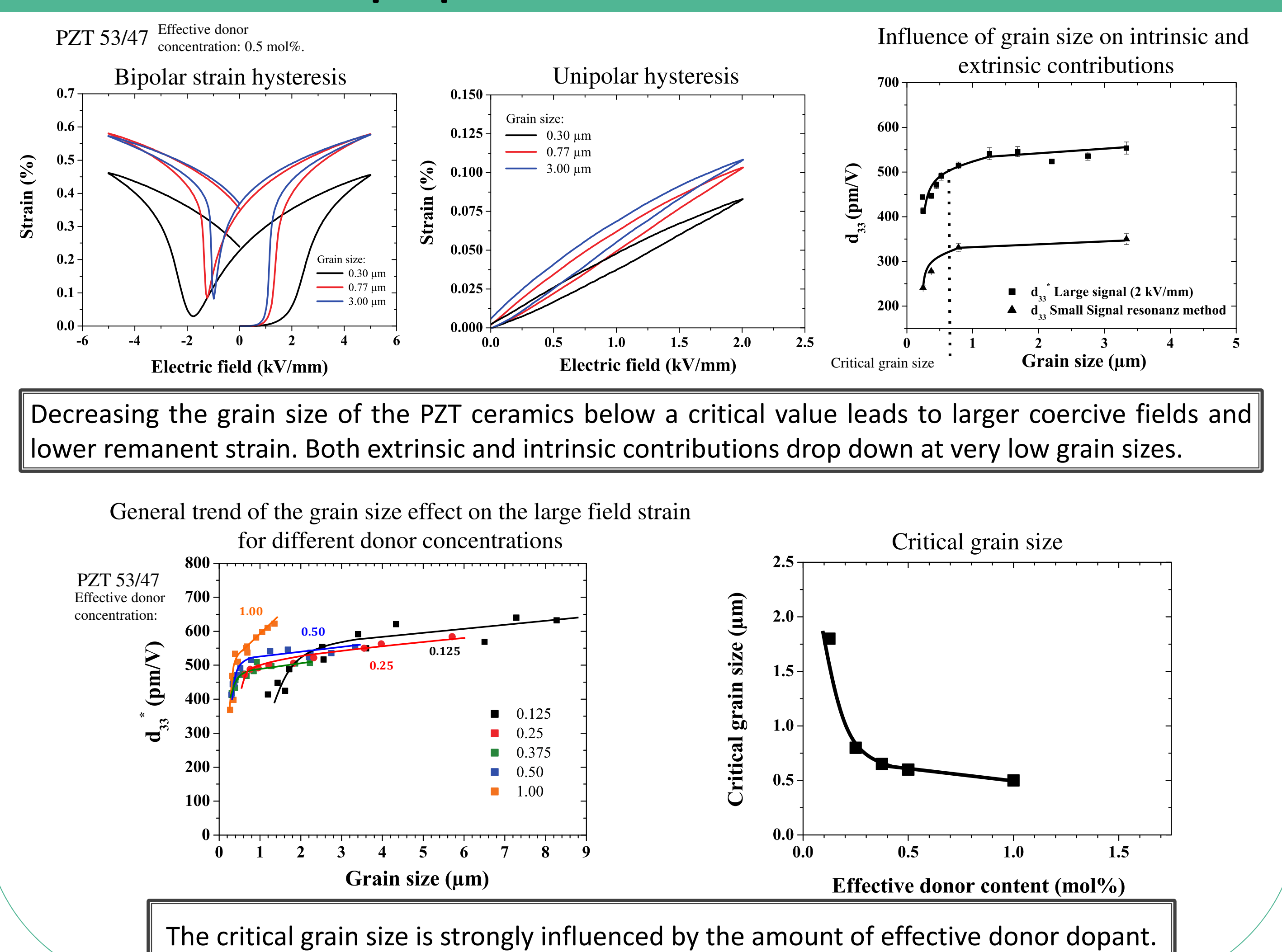
PFM analysis of the domain structure



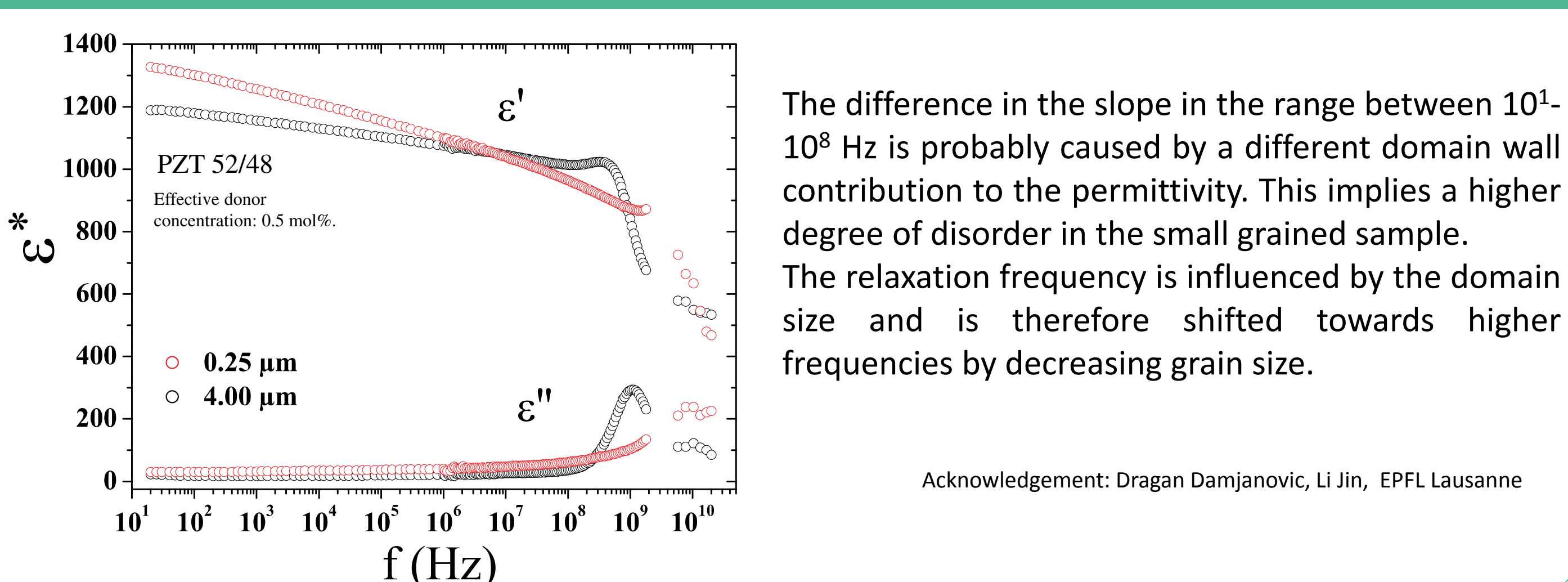
Crystal structure



Electromechanical properties



Frequency dispersion of the permittivity



Conclusions

A decrease in the grain size leads to a change in the complexity of the domain structure. The performed x-ray analysis shows a decreasing c/a-ratio for smaller grain sizes. This can be explained by an increase of the domain wall density and the pseudocubic structure close to the domain walls. This is in agreement with the frequency dependence of the permittivity showing a larger slope for a small grain size which implies a more disordered structure. The change in the domain structure and lattice parameter cause a decrease in the electromechanical properties. Below a critical grain size the intrinsic and extrinsic contributions are strongly reduced. The critical grain size is affected by the effective donor content.